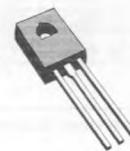


MEDIUM POWER LINEAR AND SWITCHING APPLICATIONS

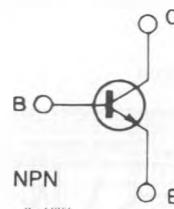
DESCRIPTION

The BD135, BD137, BD139 are silicon epitaxial planar NPN transistors in Jedec TO-126 plastic package, designed for audio amplifiers and drivers using complementary or quasi complementary circuits.

The complementary PNP types are the BD136, BD138 and BD140 respectively.



TO-126

INTERNAL SCHEMATIC DIAGRAM

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	BD135	BD137	BD139	Unit
V_{CEO}	Collector-base Voltage ($I_E = 0$)	45	60	80	V
V_{CEO}	Collector-emitter Voltage ($I_B = 0$)	45	60	80	V
V_{EBO}	Emitter-base Voltage ($I_C = 0$)		5		V
I_C	Collector Current		1.5		A
I_{CM}	Collector Peak Current		3		A
I_B	Base Current		0.5		A
P_{tot}	Total Power Dissipation at $T_{case} \leq 25^\circ\text{C}$ $T_{amb} \leq 25^\circ\text{C}$		12.5 1.25		W W
T_{stg}	Storage Temperature		-55 to 150		°C
T_J	Junction Temperature		150		°C

THERMAL DATA

$R_{th(j-case)}$	Thermal Resistance Junction-case	Max	10	°C/W
------------------	----------------------------------	-----	----	------

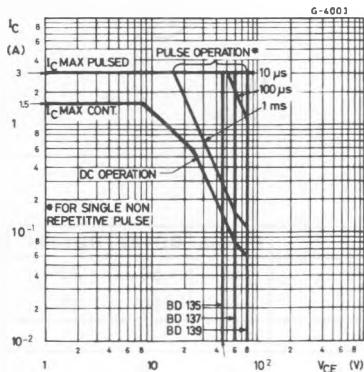
ELECTRICAL CHARACTERISTICS ($T_{case} = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector Cutoff Current ($I_E = 0$)	$V_{CB} = 30\text{V}$ $T_{case} = 125^\circ\text{C}$ $V_{CB} = 30\text{V}$			0.1	μA
I_{EBO}	Emitter Cutoff Current ($I_C = 0$)	$V_{EB} = 5\text{V}$			10	μA
$V_{CEO(sus)}^*$	Collector-emitter Sustaining Voltage ($I_B = 0$)	$I_C = 30\text{mA}$ for BD135 for BD137 for BD139	45			V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = 500\text{mA}$	$I_B = 50\text{mA}$		0.5	V
V_{BE}^*	Base-emitter on Voltage	$I_C = 0.5\text{A}$	$V_{CE} = 2\text{V}$		1	V
h_{FE}^*	DC current Gain	$I_C = 5\text{mA}$ $I_C = 0.5\text{A}$ All Types $I_C = 150\text{mA}$ for BD135 for BD137, BD139	$V_{CE} = 2\text{V}$ $V_{CE} = 2\text{V}$ $V_{CE} = 2\text{V}$	25 25 40 40	250 160	

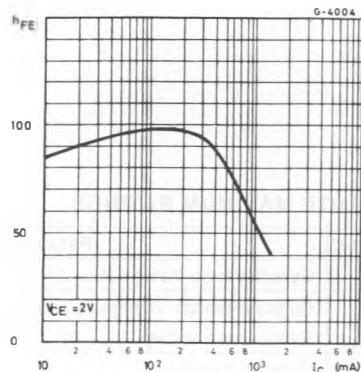
* Pulsed : pulse duration = 300μs, duty cycle < 2%.

Available in h_{FE} groups ($I_C = 150\text{mA}$; $V_{CE} = 2\text{V}$)	Min.	Max.
h _{FE} group 6	40	100
10	63	160
16	100	250

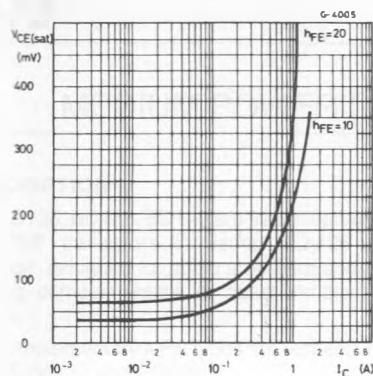
Safe Operating Area



DC Current Gain



Collector-emitter Saturation Voltage.



Base-emitter Voltage.

